## Wide Gap Slotted Optical Switch

OPB800 (L and W Series)

- $0.375^{\prime \prime}$ ( 9.525 mm ) wide gap
- Choice of aperture size
- Choice of minimum photocurrent
- Choice of opaque or IR transmissive shells
- Available for PCBoard mounting or with 24 " 26 AWG wires



## Description:

The OPB800L series, PCBoard mounting, of wide gap switch provides the flexibility of a custom device from a standard product line, while the OPB800W series, remote mounted, switch offers 24 " ( 610 mm ) 26 AWG wire interconnect.

Building from a standard housing that utilizes a $0.375^{\prime \prime}$ ( 9.5 mm ) wide slot, a user can specify the electrical output parameters, discrete shell material and the aperture width.

Housings are made from an opaque grade of injection-molded plastic that minimizes the assembly's sensitivity to visible and near-infrared ambient radiation. Discrete shells, which are exposed on parallel faces inside the device throat, are made of IR transmissive plastic (for applications where aperture contamination may occur) or of opaque plastic with aperture openings (for maximum protection against ambient light).

## Applications:

- Non-contact interruptive object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety


## CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' VibraTite for thread-locking. ND Vibra-Tite VC-3 evaporates fast without causing structural failure in OPTEK's molded plastics.


## Electrical Specifications

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Storage and Operating Temperature <br> L Series <br> W Series | $-40{ }^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| :--- | ---: |
| ${ }^{\circ} \mathrm{C}$ |  |
| Lead Soldering Temperature $[1 / 16 \text { inch }(1.6 \mathrm{~mm}) \text { from the case for } 5 \text { sec. with soldering iron }]^{(2)}$ | $-400^{\circ} \mathrm{C}$ |

Input Diode

| Forward DC Current | 50 mA |
| :--- | ---: |
| Peak Forward Current $(1 \mu$ s pulse width, 300 pps$)$ | 3 A |
| Reverse DC Voltage | 2 V |
| Power Dissipation ${ }^{(1)}$ | 100 mW |

Output Phototransistor

| Collector-Emitter Voltage | 30 V |
| :--- | :---: |
| Emitter-Collector Voltage | 5 V |
| Collector DC Current | 30 mA |
| Power Dissipation ${ }^{(1)}$ | 100 mW |



## Electrical Specifications

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS |
| :--- | :---: | :---: | :---: | :---: | :---: |

Input Diode

| $\mathrm{V}_{\mathrm{F}}$ | Forward Voltage | - | - | 1.7 | V | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| :---: | :--- | :---: | :---: | :---: | :---: | :--- |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | - | - | 100 | $\mu \mathrm{~A}$ | $\mathrm{~V}_{\mathrm{R}}=2 \mathrm{~V}$ |

## Output Phototransistor

| $\mathrm{V}_{\text {(BR)CEO }}$ | Collector-Emitter Breakdown Voltage | 30 | - | - | V | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ |
| :---: | :--- | :---: | :---: | :---: | :---: | :--- |
| $\mathrm{~V}_{\text {(BR)ECO }}$ | Emitter-Collector Breakdown Voltage | 5 | - | - | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}$ |
| $\mathrm{I}_{\text {CEO }}$ | Collector-Emitter Dark Current | - | - | 100 | nA | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}$ |

Combined

| $\mathrm{V}_{\text {CE(SAT) }}$ | Collector-Emitter Saturation Voltage  <br> Parameter A (OPB800,OPB810) <br> Parameter B (OPB801,OPB811) <br> Parameter C (OPB802,OPB812) |  | - | $\begin{aligned} & 0.4 \\ & 0.4 \\ & 0.6 \end{aligned}$ | $\begin{aligned} & \text { v } \\ & \text { v } \\ & \text { v } \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=250 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=500 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=1800 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $I_{\text {coon) }}$ | On-State Collector Current  <br> Parameter A (OPB800,OPB810) <br> Parameter B (OPB801,OPB811) <br> Parameter C (OPB802,OPB812) | $\begin{gathered} 0.625 \\ 1.25 \\ 2.25 \end{gathered}$ | - | - | mA | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=0.6 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \end{aligned}$ |

Notes:
(1) Derate linearly $1.67 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(2) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
(3) All parameters tested using pulse technique.
(4) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.
(5) The W Series includes wire terminations of $24^{\prime \prime}(610 \mathrm{~mm}) 7$-strand, 26 AWG UL insulated wire on each terminal. Each device incorporates a wire strain relief at the housing surface. The insulation functions and colors are: anode (red), cathode (black), phototransistor collector (white) and phototransistor emitter (green).

## Performance






## T <br> Electronics

OPB800 (L and W Series)

## Performance






